

### MAGB-102327-010B0P

#### Rev. V1

#### Features

- Suitable for Linear and Saturated Applications
- Optimized for Cellular Base Station Applications
- Designed for Digital Predistortion Error Correction Systems
- High Terminal Impedances for Broadband
  Performance
- 48 V Operation
- 100 % RF Tested
- RoHS\* Compliant

### Description

The MAGB-102327-010B0P is a wideband GaN HEMT D-mode amplifier designed for base station applications and optimized for 2.3 - 2.7 GHz modulated signal operation. This device supports pulsed and linear operation with peak output levels to 8 W (39 dBm) in a 4x4mm DFN package.

### **Typical Performance**

•  $V_{DS} = 48 \text{ V}, I_{DQ} = 20 \text{ mA}, T_C = 25^{\circ}\text{C}$ . Measured under load-pull at 2.5 dB compression, 100 µs pulse width, 10% duty cycle.

Frequency (GHz)	Output Power <sup>1</sup> (dBm)	Gain <sup>2</sup> (dB)	η <sub>D</sub> <sup>2</sup> (%)
2.3	38.9	16.7	72.2
2.5	39.0	17.0	71.9
2.7	38.8	16.8	73.8

1. Load impedance tuned for maximum output power.

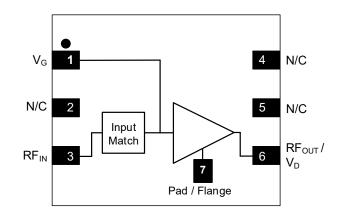
2. Load impedance tuned for maximum drain efficiency.

### **Ordering Information**

Part Number	Package
MAGB-102327-010B0P	Bulk Quantity
MAGB-102327-010BTP	Tape and Reel
MAGB-1B2327-010B0P	Class-AB Sample Board



### **Functional Schematic**



### Pin Configuration<sup>3</sup>

Pin #	Pin Name	Function
1	V <sub>G</sub>	Gate
2,4,5	N/C	No Connection
3	RF <sub>IN</sub>	RF Input
6	RF <sub>OUT</sub> / V <sub>D</sub>	RF Output / Drain
7	Pad <sup>2</sup>	Ground / Source

3. The pad on the package bottom must be connected to RF, DC or thermal ground.

\* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

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RF Electrical Characteristics: T<sub>CASE</sub> = 25°C, V<sub>DS</sub> = 48V, I<sub>DQ</sub> = 20 mA Note: Performance in MACOM Single-ended Class-AB Evaluation Circuit, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed <sup>4</sup> , 2.7 GHz	G <sub>SS</sub>	-	17.2	-	dB
Saturated Output Power	Pulsed <sup>4</sup> , 2.7 GHz	P <sub>SAT</sub>	-	38.4	-	dBm
Drain Efficiency at Saturation	Pulsed <sup>4</sup> , 2.7 GHz	$\eta_{SAT}$	-	72.2	-	%
AM/PM	Pulsed <sup>4</sup> , 2.7 GHz	Φ	-	-4	-	0
Modulated Peak Power	WCDMA <sup>5</sup> , 2.7 GHz	P2.5dB <sup>6</sup>	-	38.7	-	dBm
Gain Flatness in 60MHz	WCDMA <sup>5</sup> , P <sub>OUT</sub> = 27 dBm	G <sub>F</sub>	-	0.3	-	dB
Gain Variation (-25°C to +105°C)	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 27 dBm	ΔG	-	0.02	-	dB/°C
Power Variation (-25°C to +105°C)	Pulsed <sup>4</sup> , 2.7 GHz	$\Delta$ P2.5dB	-	0.01	-	dBm/°C
Power Gain	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 27 dBm	G <sub>P</sub>	-	16.8	-	dB
Drain Efficiency	WCDMA <sup>5</sup> , 2.7 GHz, P <sub>OUT</sub> = 27 dBm	η	-	23.3	-	%
Output CCDF @ 0.01%	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 27 dBm	PAR	-	9.5	-	dB
Adjacent Channel Power	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 27 dBm	ACP	-	-49	-	dBc
Input Return Loss	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 27 dBm	IRL	-	-5	-	dB
Ruggedness: Output Mismatch	All phase angles	Ψ	VSWR	= 10:1, No	Device [	Damage

### RF Electrical Characteristics: $T_A = 25^{\circ}C$ , $V_{DS} = 48V$ , $I_{DQ} = 20$ mA Note: Performance in MACOM Single-ended Class-AB Production Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Power Gain	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 31 dBm	G <sub>P</sub>	13.7	15.2	-	dB
Drain Efficiency	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 31 dBm	η	26	31.3	-	%
Output CCDF @ 0.01%	WCDMA <sup>5</sup> , 2.7 GHz, $P_{OUT}$ = 31 dBm	PAR	6.7	7.1	-	dB
Adjacent Channel Power	WCDMA <sup>5</sup> , 2.7 GHz, P <sub>OUT</sub> = 31 dBm	ACP	-	-38	-35	dBc
Input Return Loss	WCDMA <sup>5</sup> , 2.7 GHz, P <sub>OUT</sub> = 31 dBm	IRL	-	-5	-3	dB

### DC Electrical Characteristics: T<sub>c</sub> = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	$V_{GS}$ = -8 V, $V_{DS}$ = 130 V	I <sub>DLK</sub>	-	-	0.96	mA
Gate-Source Leakage Current	$V_{GS}$ = -8 V, $V_{DS}$ = 0 V	I <sub>GLK</sub>	-	-	-0.96	mA
Gate Threshold Voltage	$V_{DS}$ = 48 V, $I_{D}$ = 0.96 mA	VT	-2.6	-2.4	-	V
Gate Quiescent Voltage	V <sub>DS</sub> = 48 V, I <sub>D</sub> = 20 mA	V <sub>GSQ</sub>	-2.4	-2.0	-	V
On Resistance	$V_{GS}$ = 2 V, I <sub>D</sub> = 9.6 mA	R <sub>ON</sub>	-	4.3	-	Ω
Maximum Drain Current	$V_{DS}$ = 7 V, pulse width 300 µs	I <sub>D, MAX</sub>	-	0.6	-	А

 Pulse details: 100 µs pulse width, 1 ms period, 10% Duty Cycle
 Modulated Signal: 3.84MHz, WCMDA 3GPP TM1 64 DPCH, 9.9dB PAR @ 0.01% CCDF
 P2.5dB = P<sub>out</sub> + 7.5 dB where P<sub>out</sub> is the average output power measured using a modulated signal<sup>5</sup> where the output PAR is compressed to 7.5 dB @ 0.01% probability CCDF.

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## Absolute Maximum Ratings 7,8,9,10,11

Parameter	Absolute Maximum		
Drain Source Voltage, V <sub>DS</sub>	130 V		
Gate Source Voltage, V <sub>GS</sub>	-10 to 3 V		
Gate Current, I <sub>G</sub>	1.92 mA		
Storage Temperature Range	-65°C to +150°C		
Case Operating Temperature Range	-40°C to +120°C		
Channel Operating Temperature Range, T <sub>CH</sub>	-40°C to +210°C		
Absolute Maximum Channel Temperature	+225°C		

7. Exceeding any one or combination of these limits may cause permanent damage to this device.

MACOM does not recommend sustained operation above maximum operating conditions. 8.

Operating at drain source voltage V<sub>DS</sub> < 55 V will ensure MTTF > 4 x 10<sup>6</sup> hours.
 Operating at nominal conditions with T<sub>CH</sub> ≤ 210°C will ensure MTTF > 4 x 10<sup>6</sup> hours.
 MTTF may be estimated by the expression MTTF (hours) = A e<sup>[B + C/(T+273)]</sup> where *T* is the channel temperature in degrees Celsius, A = 1.76, B = -33.83, and C = 23,476.

### Thermal Characteristics<sup>12</sup>

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis	V <sub>DS</sub> = 48 V, T <sub>C</sub> = 85°C, T <sub>CH</sub> = 225°C	R <sub>θ</sub> (FEA)	27.3	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V <sub>DS</sub> = 48 V, T <sub>C</sub> = 85°C, T <sub>CH</sub> = 225°C	$R_{\theta}(IR)$	20.0	°C/W

12. Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement

### Handling Procedures

Please observe the following precautions to avoid damage:

#### Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1A, CDM Class 3 devices.

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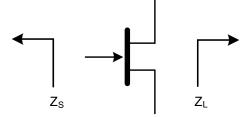
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## Pulsed<sup>4</sup> Load-Pull Performance Reference Plane at Device Leads

		Maximum Output Power						
			V <sub>DS</sub> = 48 V, I <sub>DQ</sub> = 20 mA, T <sub>c</sub> = 25°C, P2.5dB					
Frequency (GHz)	Z <sub>SOURCE</sub> (Ω)	Z <sub>LOAD</sub> <sup>13</sup> (Ω)	Gain (dB)	Р <sub>оит</sub> (dBm)	Р <sub>оит</sub> (W)	η₀ (%)	AM/PM (°)	
2.3	50	55.1 + j40.2	15.1	38.9	7.8	58.3	-54.2	
2.5	50	50.9 + j35.9	15.0	39.0	7.9	60.0	-79.3	
2.7	50	44.9 + j30.1	14.9	38.8	7.6	60.7	-107.7	

		Maximum Drain Efficiency V <sub>DS</sub> = 48 V, I <sub>DQ</sub> = 20 mA, T <sub>C</sub> = 25°C, P2.5dB					
Frequency (GHz)	Z <sub>SOURCE</sub> (Ω)	Z <sub>LOAD</sub> <sup>14</sup> (Ω)	Gain (dB)	Р <sub>оит</sub> (dBm)	Р <sub>оит</sub> (W)	η₀ (%)	AM/PM (°)
2.3	50	36.3 + j64.9	16.7	37.9	6.0	72.2	-57.0
2.5	50	26.1 + j57.4	17.0	37.1	5.1	71.9	-78.3
2.7	50	21.1 + j50.7	16.8	36.7	4.7	73.8	-109.0

#### Impedance Reference



$$\begin{split} & Z_{\text{SOURCE}} = \text{Measured impedance presented to the input of the} \\ & \text{device at package reference plane.} \\ & Z_{\text{LOAD}} = \text{Measured impedance presented to the output of the} \\ & \text{device at package reference plane.} \end{split}$$

13. Load Impedance for optimum output power.

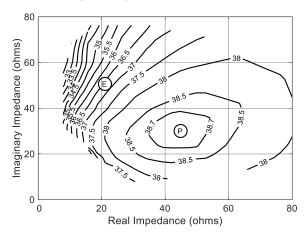
14. Load Impedance for optimum efficiency.

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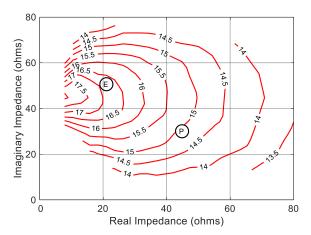


### Pulsed<sup>4</sup> Load-Pull Performance @ 2.7 GHz

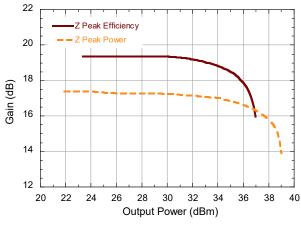
P2.5dB Loadpull Output Power Contours (dBm)



P2.5dB Loadpull Gain Contours (dB)

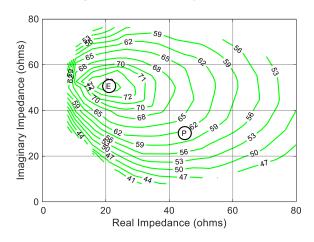


#### Gain vs. Output Power

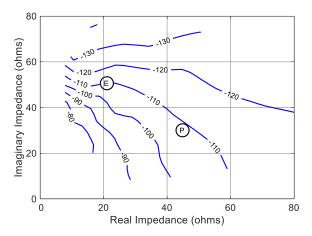


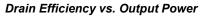
5

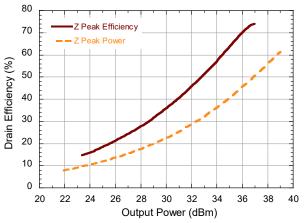
P2.5dB Loadpull Drain Efficiency Contours (%)



P2.5dB Loadpull AM/PM Contours (°)





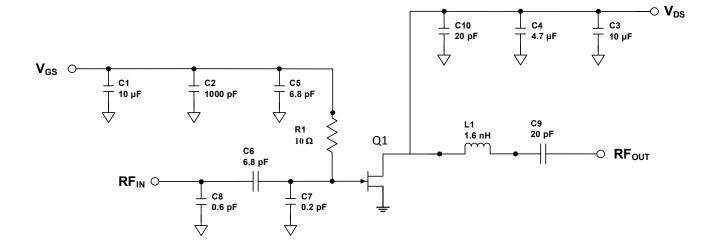


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### Evaluation Test Fixture and Recommended Tuning Solution 2.3 - 2.7 GHz

### Description

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

### Bias Sequencing Turning the device ON

- 1. Set V<sub>GS</sub> to pinch-off (V<sub>P</sub>).
- 2. Turn on V<sub>DS</sub> to nominal voltage (48 V).
- 3. Increase V<sub>GS</sub> until I<sub>DS</sub> current is reached.
- 4. Apply RF power to desired level.

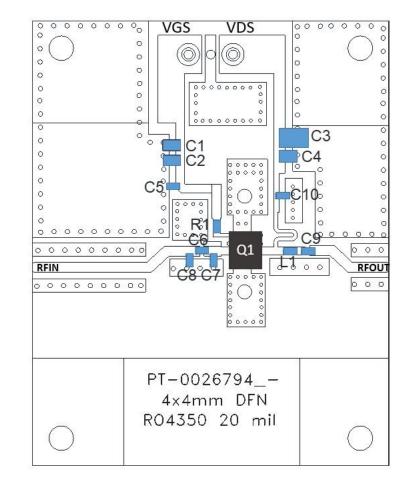
### Turning the device OFF

- 1. Turn the RF power OFF.
- 2. Decrease  $V_{GS}$  down to  $V_P$  pinch-off.
- 3. Decrease  $V_{DS}$  down to 0 V.
- 4. Turn off V<sub>GS</sub>.

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### Evaluation Board and Recommended Tuning Solution 2.3 - 2.7 GHz

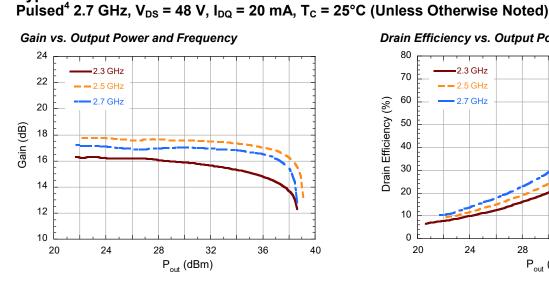
Reference Designator	Value	Tolerance	Manufacturer	Part Number		
C1	10 µF	+/- 20%	TDK Corporation	C2012X5R1C106M085AC		
C2	1000 pF	+/- 10%	KEMET	C0805C102K2RACTU		
C3	10 µF	+/- 10%	Murata	GRM32EC72A106KE05L		
C4	4.7 µF	+/- 10%	Murata	GRM21BC81H475KE11L		
C5, C6	6.8 pF	+/- 0.1pF	Murata	GQM1875C2E6R8BB12D		
C7	0.2 pF	+/- 0.1pF	Murata	GQM1875C2ER20BB12D		
C8	0.6 pF	+/- 0.1pF	Murata	GQM1875C2ER60BB12D		
C9, C10	20 pF	+/- 5%	Murata	GQM1875C2E200JB12D		
L1	1.6 nH	+/- 5%	Coilcraft	0603CS-1N6XJEW		
R1	10 Ω	+/- 0.5%	Yageo	RT0805DRE0710RL		
PCB	RO4350, 20mil, 1oz Cu, Au Finish					

<sup>7</sup> 

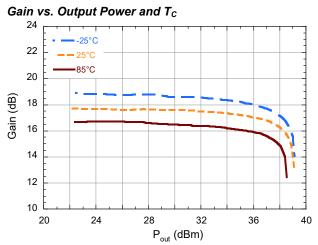
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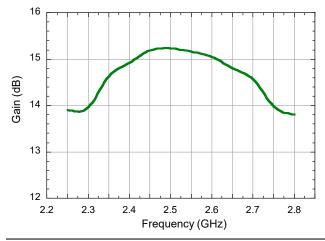
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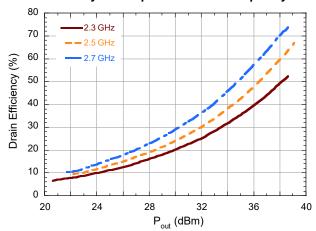
Typical Performance Curves as Measured in the 2.3 - 2.7 GHz Evaluation Board:



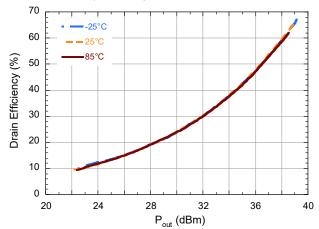
Gain vs. Frequency, 2.5dB Gain Compression



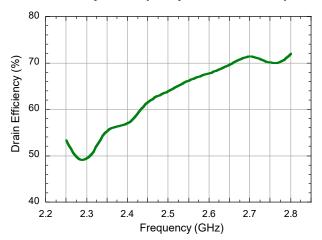
Drain Efficiency vs. Output Power and Frequency



Drain Efficiency vs. Output Power and T<sub>c</sub>



Drain Efficiency vs. Frequency, 2.5dB Gain Compression



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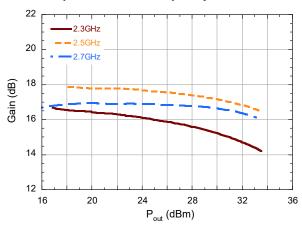


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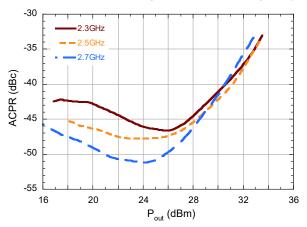
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## Typical Performance as Measured in the 2.3 - 2.7 GHz Evaluation Board: WCMDA 3GPP TM1 64 DPCH 9.9 dB PAR @ 0.01% CCDF, $V_{DS}$ = 48 V, $I_{DQ}$ = 20 mA, $T_{C}$ = 25°C

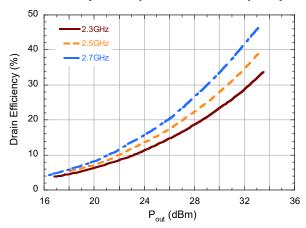
Gain vs. Output Power and Frequency



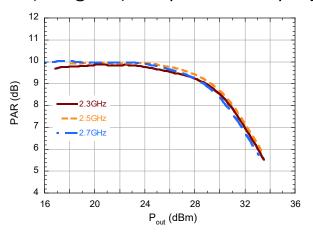
ACPR (Max ±5 MHz) vs. Output Power and Frequency



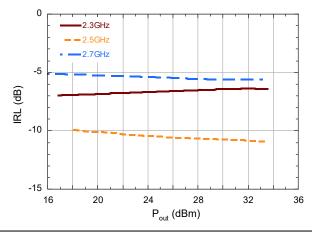
Drain Efficiency vs. Output Power and Frequency



PAR (CCDF @ 0.01%) vs. Output Power and Frequency



Input Return Loss vs. Output Power and Frequency



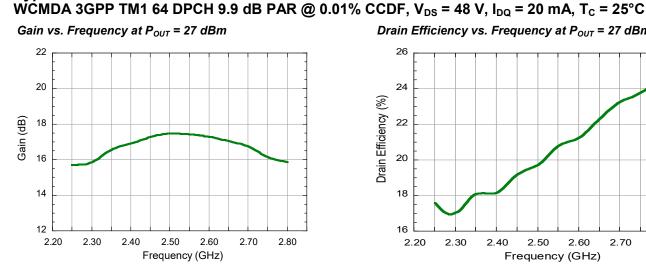
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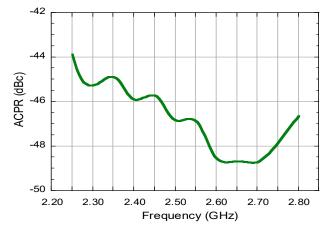
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Typical Performance as Measured in the 2.3 - 2.7 GHz Evaluation Board:

ACPR (Max ±5 MHz) vs. Frequency at Pout = 27 dBm



Frequency (GHz)

2.50

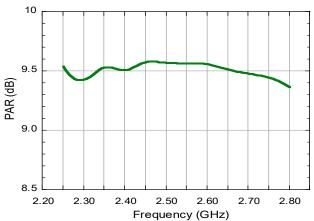
2.60

2.70

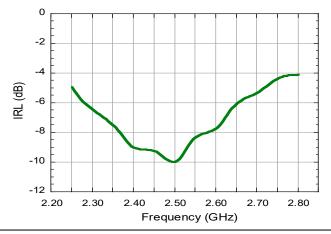
2.80

2.40





Input Return Loss vs. Frequency at Pour = 27 dBm



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Drain Efficiency vs. Frequency at Pout = 27 dBm 26

24

22

20

18

16

2.20

2.30

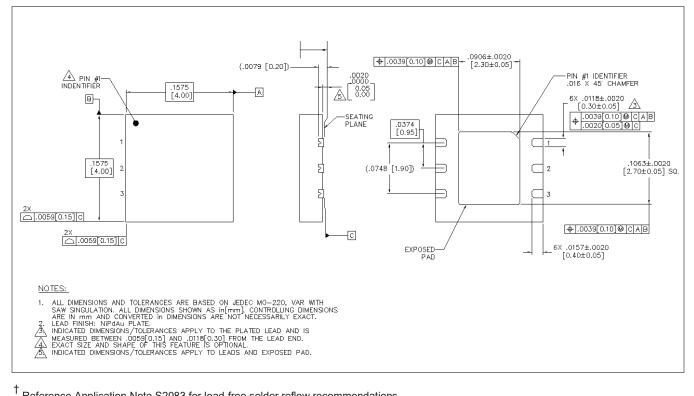
Drain Efficiency (%)



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### Lead-Free 4 x 4 mm 6-Lead Package Dimensions<sup>†</sup>



Reference Application Note S2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level (MSL) 3 requirements.

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